



High Speed, Low Voltage, 3 Ω, Differential 4:1 CMOS Analog Multiplexer/Switch

DESCRIPTION

The DG2707 is a high speed, low voltage, 3 Ω , differential 4:1 multiplexer. It operates from a 1.65 V to 4.3 V single power supply. All channels guaranteed break before make switching. When powered with single 3.15 V supply, channel to channel ON Resistance matching is within 0.3 Ω .

All control logic input has 0.5 V to 1.65 V threshold. The EN pin enables cascading of the multiplexers. It features a 120 MHz - 3 dB bandwidth, - 90 dB crosstalk and - 70 dB off-isolation at 1 MHz.

The DG2707 comes in a small miniQFN-16 lead package (1.8 mm x 2.6 mm x 0.75 mm). As a committed partner to community and the environment, Vishay Siliconix manufactures this product with the lead (Pb)-free device terminations and is 100 % RoHS complicant.

FEATURES

- Low voltage operation (1.65 V to 4.3 V)
- Low on-resistance R_{ON} : 2.8 Ω typ. at 3.15 V
- Low voltage logic threshold
- Low crosstalk: 70 dB
- High off-isolation: 90 dB
- Ultra small package: miniQFN16 of 1.8 mm x 2.6 mm



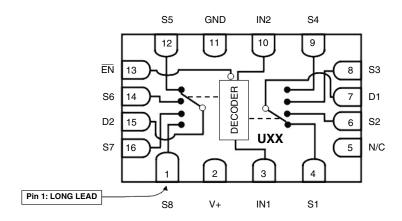
ROHS

APPLICATIONS

- · A/V and analog signal routing
- · Battery operated devices
- · Data acquisition systems
- · Communications systems
- · Medical and ATE equipments

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

miniQFN-16L



Top View

Device Marking: UXX Traceability Code: U is DG2707DN XX = Date/Lot

ORDERING INFORMATION				
Temp. Range	Package	Part Number		
- 40 °C to 85 °C	miniQFN-16	DG2707DN-T1-E4		

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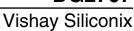


TRUTH TABLE DG2707 MULTIPLEXER, MINIQFN-16L						
Enable Input	able Input Select Input		On Switches (Pin)			
EN (Pin 13)	IN2 (Pin 10)	IN1 (Pin 3)	Description (Pin)	Common (Pin)		
0	0	0	S5 (Pin 12)			
0	0	1	S6 (Pin 14)	D0 (Din 15)		
0	1	0	S7 (Pin 16)	D2 (Pin 15)		
0	1	1	S8 (Pin 1)			
0	0	0	S1 (Pin 4)			
0	0	1	S2 (Pin 6)	D4 /Bin 7\		
0	1	0	S3 (Pin 8)	D1 (Pin 7)		
0	1	1	S4 (Pin 9)			
1	Х	Х	All Switches are off			
Pin 5 N/C						

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)					
Parameter		Limit	Unit		
Reference to GND	V+	- 0.3 to 5.0	V		
Reference to GND	EN, IN, D _X , S _X ^a	- 0.3 to (V+ + 0.3)	7		
Current (Any terminal except S _X or D _X)		30			
Continuous Current (S _X or D _X)		± 300	mA		
Peak Current (Pulsed at 1 ms, 10 % Duty	y Cycle)	± 500			
Storage Temperature (D Suffix)		- 65 to 150	°C		
Thermal Resistance (Package) ^b	miniQFN-16	152	°C/W		
Power Dissipation (Packages) ^b miniQFN-16 ^{c, d}		525	mW		

Notes:

- $a. \ Signals \ on \ S_X \ or \ D_X, \ or \ IN_X \ or \ EN \ exceeding \ V+ \ will \ be \ clamped \ by \ internal \ diodes. \ Limit \ forward \ diode \ current \ to \ maximum \ current \ ratings.$
- b. All leads welded or soldered to PC board.
- c. Derate 6.6 mW/°C above 70 °C
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.





SPECIFICATIONS (V+ = 3.15 V)								
				Limits				
		Test Conditions			°C to 8			
Parameter	Symbol	Otherwise Unless Specified	Temp.b	Min.a	Typ. ^c	Max. ^a	Unit	
Analog Switch				1				
Analog Signal Range ^e	V _{analog}	R _{DS(on)}	Full	0		V+	V	
On Resistance	R _{DS(on)}	$V+ = 3.15 \text{ V}, \text{ IS}_X = 10 \text{ mA}, \text{ VD}_X = 1.0 \text{ V}$	Room		2.8	5.5 6		
R _{ON} Match	$\Delta R_{(on)}$	$V+ = 3.15 \text{ V}, \text{ IS}_X = 10 \text{ mA}, \text{ VD}_X = 1.0 \text{ V}$	Room		0.3		Ω	
R _{ON} Resistance Flatness	R _(on) Flatness	$V+ = 3.15 \text{ V}, \text{ IS}_X = 10 \text{ mA}, \text{ VD}_X = 0.0 \text{ V}, 1.0 \text{ V}$	Room		0.6		1	
	I _{SX(off)}	$V+ = 3.6 \text{ V}, VS_X = 0.5 \text{ V}/3 \text{ V}, VD_X = 3 \text{ V}/0.5 \text{ V}$	Room	- 5		5		
Channel-Off Leakage Current	I _{DX(off)}		Full	- 10		10	1	
0	. ` '	V 00VV0 VD 0V05V	Room	- 10		10	nA	
Channel-On Leakage Current	I _{DX(on)}	$V+ = 3.6 \text{ V}, VS_X, VD_X = 3 \text{ V}/0.5 \text{ V}$	Full	- 20		20		
Digital Control				l				
Input High Voltage	V _{INH}			1.65			V	
Input Low Voltage	V _{INL}		Full			0.4		
Input Current	I _{INL} or I _{INH}	V _{IN} = 0 or V+		- 1		1	μΑ	
Input Capacitance	C _{IN}	V+ = 3.15, f = 1 MHz			5.1		pF	
Dynamic Characteristics				l				
Decale Defense Males Times			Room		1			
Break-Before-Make Time	t _{BBM} t _{ON(EN)} t _{OFF(EN)} t _{TRANS}		Full	5			ns	
			Room		20	45		
Enable Turn-On Time		VO 45V B 50 0 0 55 5	Full			55		
		$VS_X = 1.5 \text{ V}, R_L = 50 \Omega, C_L = 35 \text{ pF}$	Room		15	35		
Enable Turn-Off Time			Full			45		
T :: T			Room		35	55		
Transition Time			Full			65		
Charge Injection ^d	Q_{INJ}	$C_L = 1 \text{ nF, } R_{GEN} = 0 \Omega, VS_X = 2 V$	Room		- 14		рС	
Off-Isolation ^d	OIRR	V. 045 V £ 4 MU- D 50 0 0 5 m5			- 70		-ID	
Crosstalk ^{d, f}	X _{TALK}	$V+ = 3.15 V$, $f = 1 MHz$, $R_L = 50 \Omega$, $C_L = 5 pF$	5 pF Room		- 90		dB	
Bandwidth ^d	BW	V+ = 3.15 V, R_L = 50 Ω, C_L = 5 pF, - 3 dB	Room		120		MHz	
Total Harmonic Distortion ^d	THD	$V_{+} = 3.15 \text{ V}, R_{load} = 600 \Omega$	Room		0.02		%	
S _X , D _X Off Capacitance ^d	C _{S(off)}				16		pF	
	CD _{X(off)}	V+ = 3.15 V, f = 1 MHz	Room		42			
Channel-On Capacitance ^d	CD _{X(on)}				49			
Power Supply	V- /							
Power Supply Range	V+			1.65		4.3	V	
Power Supply Current	l+	$V_{IN} = 0 \text{ V or V} +$	Full			1	μΑ	

Notes:

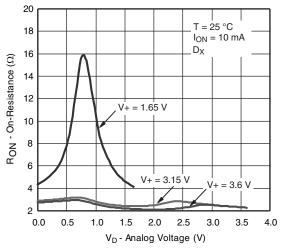
- a. Room = 25 °C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e. V_{IN} = input voltage to perform proper function.
- f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

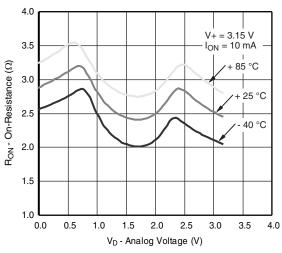
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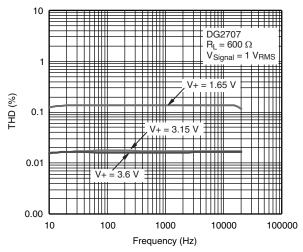
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



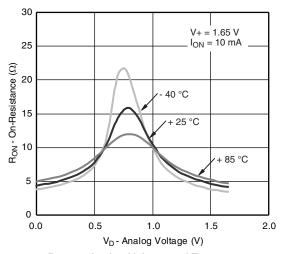
 $\rm R_{ON}$ vs. $\rm V_{D}$ and Single Supply Voltage



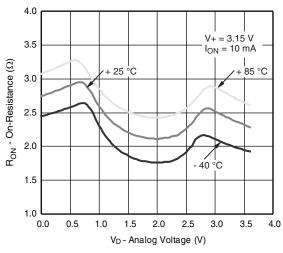
R_{ON} vs. Analog Voltage and Temperature



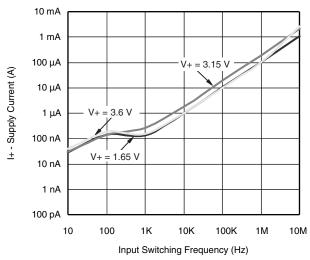
Switching Threshold vs. Supply Voltage



R_{ON} vs. Analog Voltage and Temperature



R_{ON} vs. Analog Voltage and Temperature

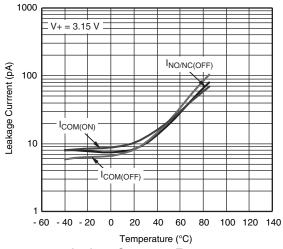


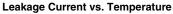
Supply Current vs. Input Switching Frequency

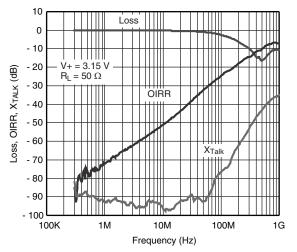




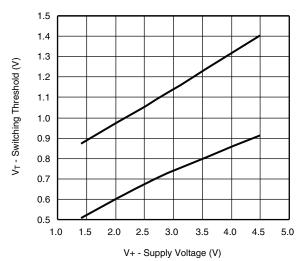
TYPICAL CHARACTERISTICS ($T_A = 25$ °C, unless otherwise noted)







Insertion Loss, Off-Isolation Crosstalk vs. Frequency

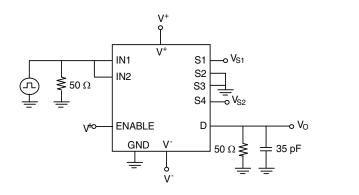


Switching Threshold vs. Supply Voltage

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TEST CIRCUITS



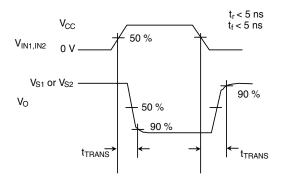
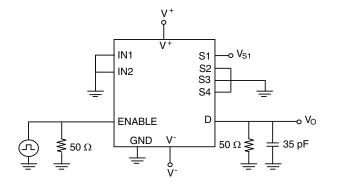


Figure 1. Transition Time



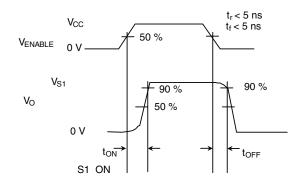
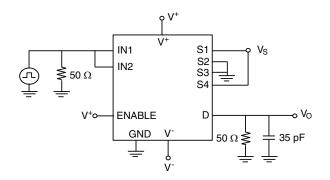


Figure 2. Enable Switching Time



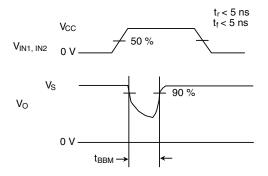


Figure 3. Break-Before Make



TEST CIRCUITS

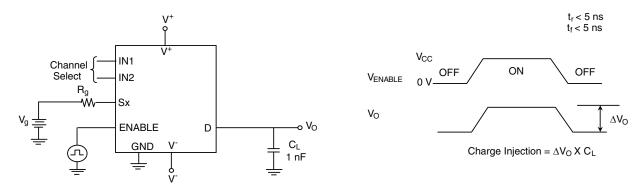


Figure 4. Charge Injection

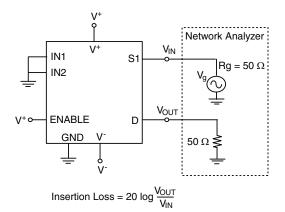


Figure 5. Insertion Loss

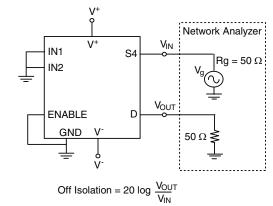


Figure 6. Off-Isolation

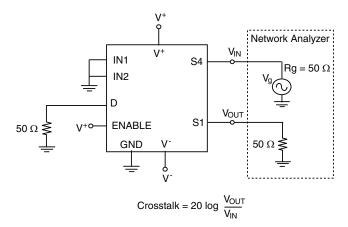


Figure 7. Crosstalk

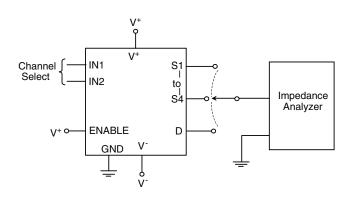
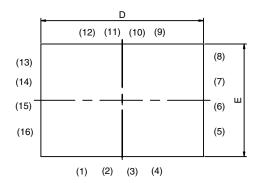


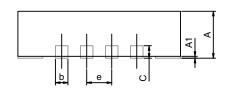
Figure 8. Source, Drain Capacitance

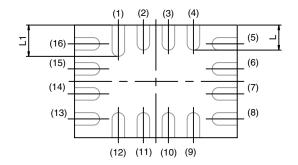
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MINI QFN-16L







BACK SIDE VIEW

DIM	MILLIMETERS			INCHES		
DIIVI	MIN.	NAM	MAX.	MIN.	NAM	MAX.
Α	0.70	0.75	0.80	0.0275	0.0295	0.0315
A1	0	-	0.05	0	-	0.002
b	0.15	0.20	0.25	0.0059	0.0078	0.0098
С	0.15	0.20	0.25	0.0059	0.0078	0.0098
D	2.60 BSC			0.1023 BSC		
Е	1.80 BSC			0.0708 BSC		
е	0.40 BSC				0.0157 BSC	;
L	0.35	0.40	0.45	0.0137	0.0157	0.0177
L1	0.45	0.50	0.55	0.0177	0.0196	0.0216

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